VS-75EPU12LHN3

Vishay Semiconductors

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Ultrafast Rectifier, 75 A FRED Pt[®]



| PRODUCT SUMMARY | | | | | | | | |
|--|-------------|--|--|--|--|--|--|--|
| Package | TO-247AD 2L | | | | | | | |
| I _{F(AV)} | 75 A | | | | | | | |
| V _R | 1200 V | | | | | | | |
| V _F at I _F at 125 °C | 1.95 V | | | | | | | |
| t _{rr} | 62 ns | | | | | | | |
| T _J max. | 175 °C | | | | | | | |
| Diode variation | Single die | | | | | | | |

FEATURES

- · Ultrafast and soft recovery time
- Optimized forward voltage drop
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Rugged design
- Good thermal performance
- AEC-Q101 gualified available
- Meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, recovery time, and soft recovery. Polyimide passivated, planar structure and the platinum doped life time control guarantee, ruggedness, reliability characteristics, and solid value proposition for efficiency and thermal performance.

These devices are intended for use in boost stage in the AC/DC section of SMPS, high frequency output rectification of battery charger, inverters of solar inverters, or as freewheeling diodes in motor drive.

| ABSOLUTE MAXIMUM RATINGS | | | | |
|--|-----------------------------------|---|-------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Repetitive peak reverse voltage | V _{RRM} | | 1200 | V |
| Average rectified forward current | I _{F(AV)} | T _C = 140 °C, D = 0.50 | 75 | |
| Non-repetitive peak surge current | I _{FSM} | $T_C = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ sine wave}$ | 700 | А |
| Repetitive peak forward current | I _{FRM} | | 150 | |
| Operating junction and storage temperature | T _J , T _{Stg} | | -55 to +175 | °C |

| ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified) | | | | | | | | | |
|--|-------------------------------------|---|------|-------|------|----|--|--|--|
| PARAMETER | MIN. | TYP. | MAX. | UNITS | | | | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | $I_{\rm P} = 1.5 \mathrm{mA}$ | | - | - | | | | |
| Forward voltage | V _F | I _F = 75 A | - | 2.05 | 2.55 | V | | | |
| Forward voltage | | I _F = 75 A, T _J = 125 °C | - | 1.95 | 2.37 | | | | |
| Poverse leakage current | | $V_R = V_R$ rated | - | - | 420 | | | | |
| Reverse leakage current | I _R | $T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$ | 87 | | 875 | μA | | | |
| Junction capacitance | CT | V _R = 200 V | - | 90 | - | pF | | | |
| Series inductance | Ls | Measured lead to lead 5 mm from package body | - | 8.0 | - | nH | | | |

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RoHS

COMPLIANT

HALOGEN

FREE





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| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified) | | | | | | | | | | |
|---|------------------|--|---|------|------|------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS | | | |
| | | $I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 10$ | 00 A/µs, V _R = 30 V | - | 62 | - | | | | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 265 | - | ns | | | |
| | | T _J = 125 °C | | - | 509 | - | | | | |
| Poole recovery ourrent | I | T _J = 25 °C | l _F = 50 A dl _F /dt = 100 A/μs | - | 10.4 | - | A | | | |
| Peak recovery current | I _{RRM} | T _J = 125 °C | $V_{\rm B} = 390 \text{ V}$ | - | 19.2 | - | | | | |
| Reverse recovery charge | 0 | T _J = 25 °C | | - | 1390 | - | nC | | | |
| neverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 4900 | - | nc | | | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | | | |
|--|-----------------------------------|---|--------------|-------|------------|------------------------|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | | |
| Thermal resistance, junction to case | R _{thJC} | | - | 0.11 | 0.16 | | | | | |
| Thermal resistance, junction to ambient | R _{thJA} | Typical socket mount | - | 31 | 36 | °C/W | | | | |
| Thermal resistance, case to heat sink | R _{thCS} | Mounting surface, flat, smooth, and greased | - | 0.23 | 0.5 | | | | | |
| Weight | | | - | 0.2 | - | g | | | | |
| weight | | | - | 0.07 | - | oz. | | | | |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) | | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | 175 | °C | | | | |
| Marking device | | Case style: TO-247AD 2L | | 75EPU | J12LH | | | | | |

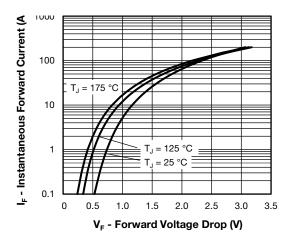


Fig. 1 - Typical Forward Voltage Drop Characteristics

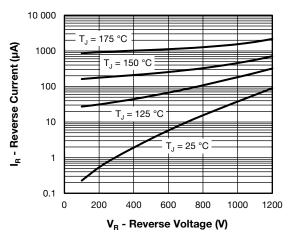


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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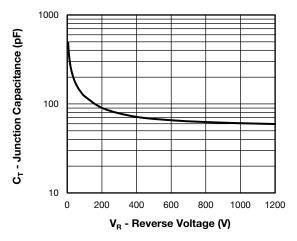


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

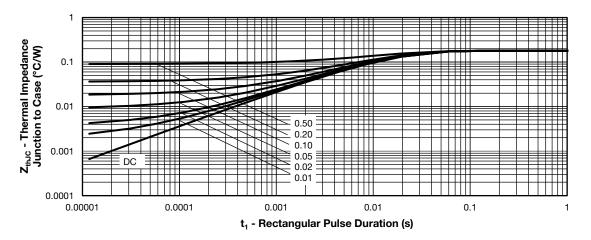


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

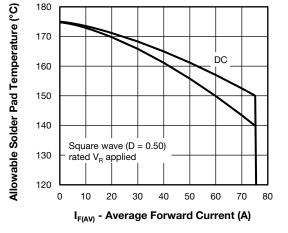


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

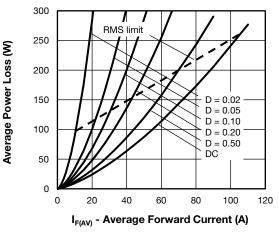


Fig. 6 - Forward Power Loss Characteristics

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300 250 50 A 200 t_{rr} (ns) 35 A 150 100 . T_J = 25 °C 50 100 150 200 250 300 350 400 450 500 dl_F/dt (A/µs)

Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

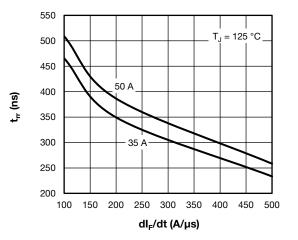


Fig. 8 - Typical Reverse Recovery Time vs. dl_F/dt

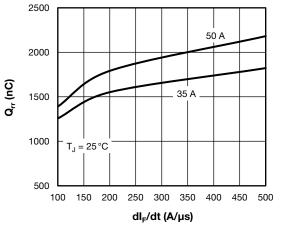


Fig. 9 - Typical Stored Charge vs. dl_F/dt

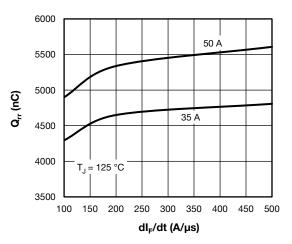


Fig. 10 - Typical Stored Charge vs. dl_F/dt

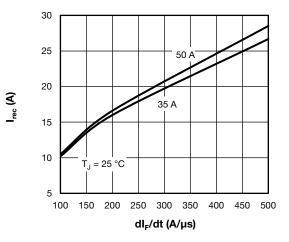


Fig. 11 - Typical Reverse Current vs. dl_F/dt

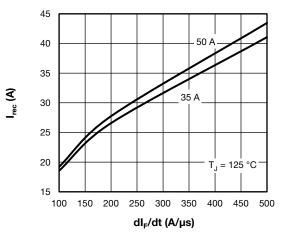


Fig. 12 - Typical Reverse Current vs. dI_F/dt

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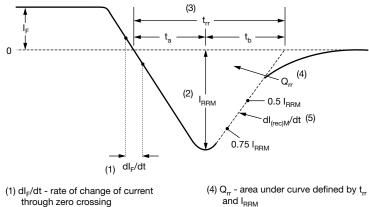
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(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 $\mathrm{I}_{\mathrm{RRM}}$ and 0.50 $\mathrm{I}_{\mathrm{RRM}}$ extrapolated to zero current.

and I_{RRM}

 $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 13 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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| Device code | VS- | 75 | Е | Р | U | 12 | L | Н | N3 |
|-------------|---------------------------------------|------|----------|----------|-----------|---------|-----------|-----------|---------|
| | | (2) | (3) | (4) | (5) | (6) | (7) | (8) | (9) |
| | 1 - | Visł | nay Sem | niconduc | ctors pro | oduct | C | 0 | |
| | 2 - Current rating (75 = 75 A) | | | | | | | | |
| | 3 - E = single diode | | | | | | | | |
| | 4 - | Pac | kage: | | | | | | |
| | | P = | TO-247 | , | | | | | |
| | 5 - | U = | ultrafas | t recove | ery | | | | |
| | 6 - | Volt | age rati | ng (12 = | = 1200 V | /) | | | |
| | 7 - L = long leads | | | | | | | | |
| | 8 - H = AEC-Q101 qualified | | | | | | | | |
| | 9 - Environmental digit: | | | | | | | | |
| | | N3 | = haloge | en-free, | RoHS-c | complia | nt, and t | otally le | ad (Pb) |

| ORDERING INFORMATION (Example) | | | | | | | | | |
|--------------------------------|-------------------|------------------------|-------------------------|--|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER TUBE | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | | |
| VS-75EPU12LHN3 | 25 | 500 | Antistatic plastic tube | | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | |
|----------------------------|--------------------------|--|--|--|--|--|
| Dimensions | www.vishay.com/doc?95536 | | | | | |
| Part marking information | www.vishay.com/doc?95648 | | | | | |

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TO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

(b, b2)

(4)

| View | <u>/ B</u> |
|------|------------|

| SYMBOL | MILLIN | IETERS | INCHES | | NOTES | SYMBOL | MILLIMETERS | | INCHES | | NOTES | |
|----------|--------|--------|--------|-------|-------|--------|-------------|-------|--------|-------|-------|-------|
| STIVIDUL | MIN. | MAX. | MIN. | MAX. | NOTES | | STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.65 | 5.31 | 0.183 | 0.209 | | | E | 15.29 | 15.87 | 0.602 | 0.625 | 3 |
| A1 | 2.21 | 2.59 | 0.087 | 0.102 | | | E1 | 13.46 | - | 0.53 | - | |
| A2 | 1.50 | 2.49 | 0.059 | 0.098 | | | е | 5.46 | BSC | 0.215 | 5 BSC | |
| b | 0.99 | 1.40 | 0.039 | 0.055 | | | ØК | 0.2 | 254 | 0.0 | 010 | |
| b1 | 0.99 | 1.35 | 0.039 | 0.053 | | | L | 19.81 | 20.32 | 0.780 | 0.800 | |
| b2 | 1.65 | 2.39 | 0.065 | 0.094 | | | L1 | 3.71 | 4.29 | 0.146 | 0.169 | |
| b3 | 1.65 | 2.34 | 0.065 | 0.092 | | | ØР | 3.56 | 3.66 | 0.14 | 0.144 | |
| С | 0.38 | 0.89 | 0.015 | 0.035 | | | Ø P1 | - | 6.98 | - | 0.275 | |
| c1 | 0.38 | 0.84 | 0.015 | 0.033 | | | Q | 5.31 | 5.69 | 0.209 | 0.224 | |
| D | 19.71 | 20.70 | 0.776 | 0.815 | 3 | | R | 4.52 | 5.49 | 0.178 | 0.216 | |
| D1 | 13.08 | - | 0.515 | - | 4 | | S | 5.51 | BSC | 0.217 | ' BSC | |
| D2 | 0.51 | 1.35 | 0.020 | 0.053 | | | | • | | • | | • |

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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Revision: 01-Jan-2024